TOSHIBA Intelligent Power Device Silicon Monolithic Power MOS Integrated Circuit

TPD1024S

Low-side Power Switch for Motors, Solenoids, and Lamp Drivers

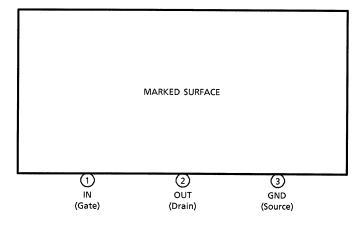
The TPD1024S is a monolithic power IC for low-side switches. The IC has a vertical MOS FET output which can be directly driven from a CMOS or TTL logic circuit (e.g., an MPU).

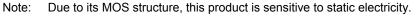
The device is equipped with an intelligent self-protection function.

Features

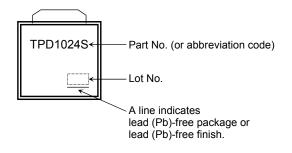
- A monolithic power IC with a new structure combining a control block and a vertical power MOS FET (π -MOS) on a single chip
- Can directly drive a power load from a CMOS logic.
- Built-in protection against overvoltage, load short-circuiting, and thermal shutdown
- Low on-resistance : RDS (ON) = 0.5 Ω (max), (@VIN = 5 V, Tj = 25°C)
- 3-pin power-molded package usable for surface mounting.

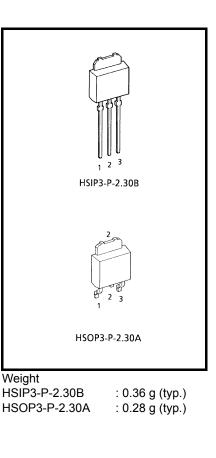
Pin Assignment



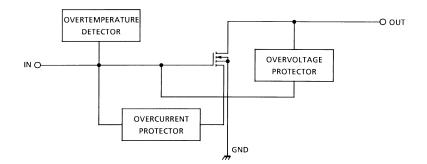


Marking





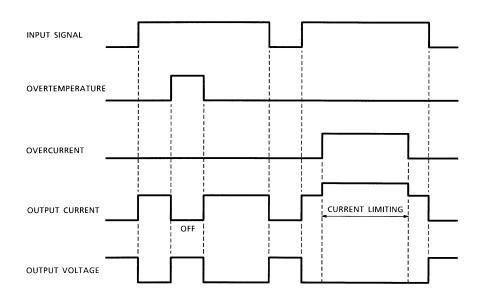
Block Diagram



Pin Description

| Pin No. | Symbol | Function |
|---------|--------|--|
| 1 | IN | Input pin. Input is CMOS-compatible, with pull-down resistor connected. Even if the input is open, output will not accidentally turn on. |
| 2 | OUT | Output pin. When current in excess of the typical current (3.5 A (typ.)) flows to the output pin, the current limiter operates to protect the IC. |
| 3 | GND | Ground pin. |

Timing Chart



Absolute Maximum Ratings (Ta = 25°C)

| Characteri | stic | Symbol | Rating | Unit | | |
|-----------------------|-----------|----------------------|-----------|------|--|--|
| Drain-source voltage | | V _{DS (DC)} | 40 | V | | |
| Output current | | I _D | 1.5 | А | | |
| Input voltage | | V _{GS} | -0.5 ~ 6 | V | | |
| Power dissipation | Ta = 25°C | Pn | 1 | W | | |
| Power dissipation | Tc = 25°C | ۳D | 10 | vv | | |
| Operating temperature | • | T _{opr} | -40 ~ 85 | °C | | |
| Junction temperature | | Тj | 150 | °C | | |
| Storage temperature | | T _{stg} | -55 ~ 150 | °C | | |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

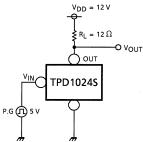
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

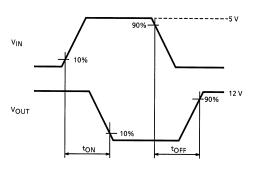
Electrical Characteristics (T_j = 25°C)

| Characteristic | Symbol | Test Cir- cuit | Test Condition | Min | Тур. | Max | Unit |
|---|-----------------------|----------------------|--|-----|------|-----|------|
| Drain-source breakdown voltage | V _(BR) DSS | | V _{GS} = 0, I _D = 10 mA | 40 | | | V |
| Operating supply voltage | V _{DD} (OPR) | | — | _ | _ | 18 | V |
| Current et eutrut eff | I _{DSS (1)} | _ | V _{GS} = 0, V _{DS} = 40 V | — | _ | 3 | mA |
| Current at output off | I _{DSS (2)} | _ | V _{GS} = 0, V _{DS} = 24 V | — | _ | 100 | μA |
| Input threshold voltage | V _{th} | _ | V _{DS} = 10 V, I _D = 1 mA | 0.8 | _ | 2.5 | V |
| Input current | IGSS | _ | V _{GS} = 5 V, at normal operation | _ | _ | 300 | μA |
| On resistance | R _{DS (ON)} | | V _{GS} = 5 V, I _D = 1 A | _ | _ | 0.5 | Ω |
| Thermal shutdown temperature | Τ _S | | — | _ | 160 | _ | °C |
| Overcurrent protection | IS | _ | V _{DS} = 12 V, V _{GS} = 5 V | — | 3.5 | _ | А |
| Quuitabin a time | t _{ON} | - 1 | V_{DS} = 12 V, V_{GS} = 5 V, R _L = 12 Ω | — | 50 | _ | μs |
| Switching time | tOFF | | | _ | 10 | — | μs |
| Diode forward voltage Between drain and source | V _{DSF} | _ | I _F = 1.5 A | _ | 0.9 | 1.8 | V |
| Avalanche energy | E _A | _ | L = 10 mH, Single pulse | 30 | — | | mJ |

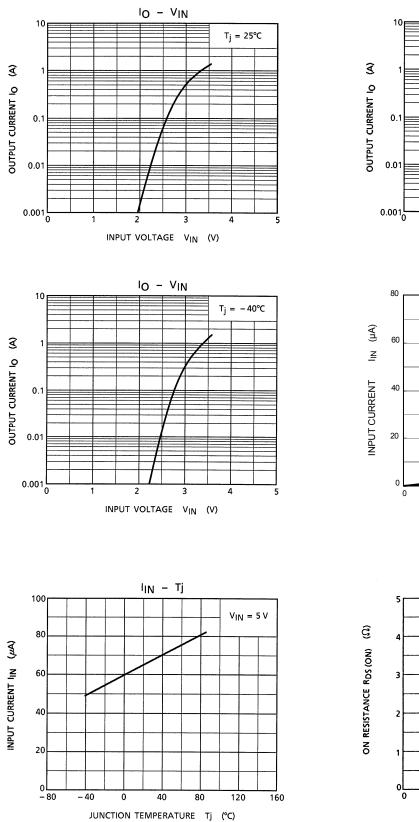
Test Circuit 1

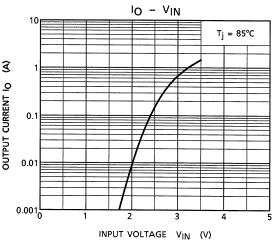


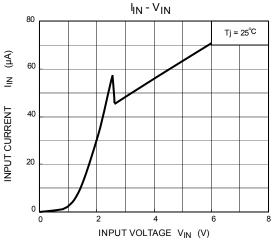


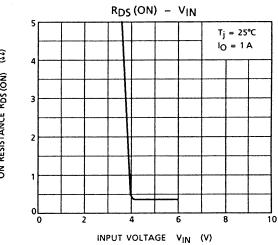


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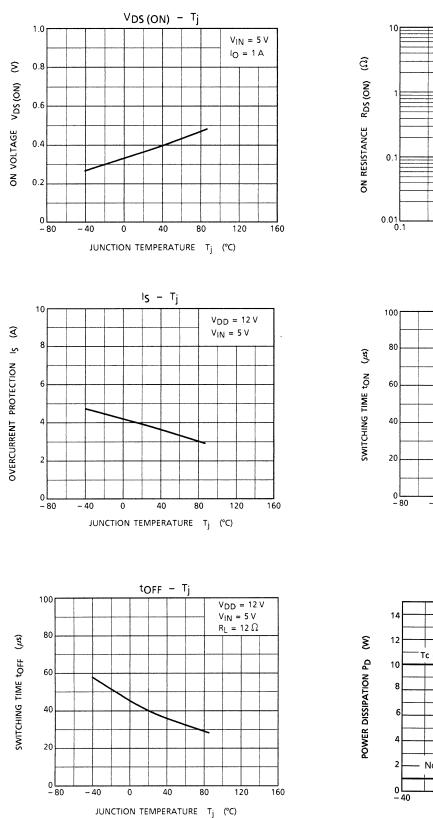


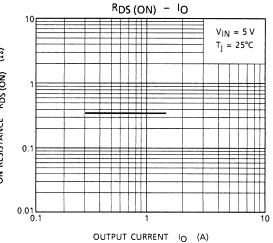


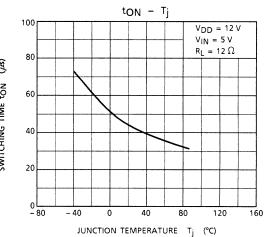


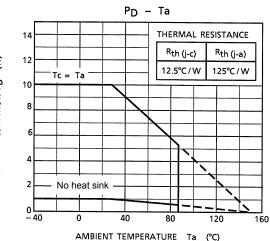


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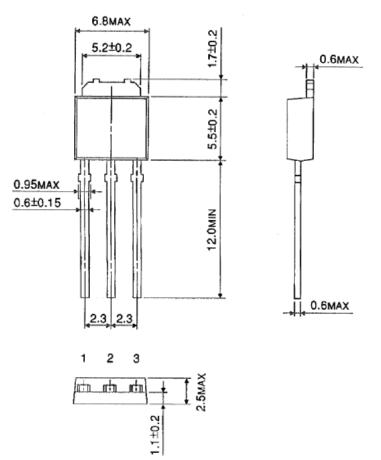


TPD1024S

Package Dimensions

TOSHIBA

HSIP3_P_2.30B



Weight: 0.36 g (typ.)

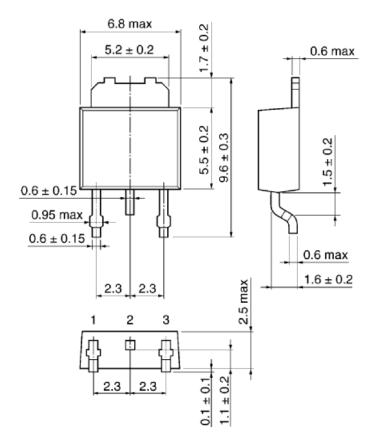
Unit: mm

TOSHIBA

Package Dimensions

HSOP3_P_2.30A

Unit: mm



Weight: 0.28 g (typ.)

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